

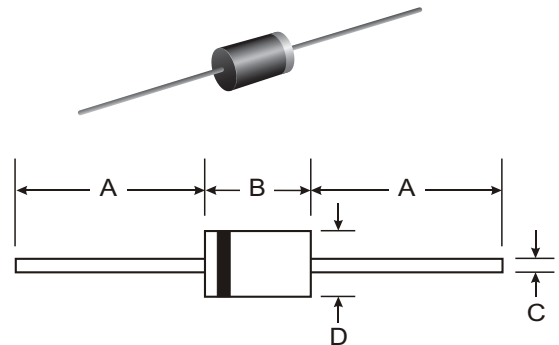
**VOLTAGE RANGE: 200 - 600V**  
**CURRENT: 0.25 A**

### Features

- Low cost
- Diffused junction
- Low leakage
- Low forward voltage drop
- High current capability
- Easily cleaned with freon, Alcohol, Isopropanol and similar solvents

### Mechanical Data

- Case: D O - 4 1 Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.34 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-41		
Dim	Min	Max
A	25.40	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

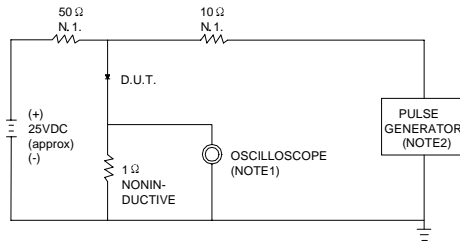
### Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

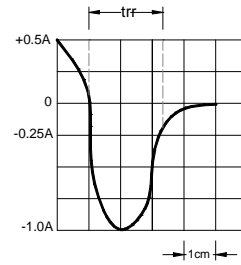
Characteristic	Symbol	EU01Z	EU01	EU01A	Unit
Maximum peak repetitive reverse voltage	$V_{RRM}$	200	400	600	V
Maximum RMS voltage	$V_{RMS}$	140	280	420	V
Maximum DC blocking voltage	$V_{DC}$	200	400	600	V
Maximum average forward rectified current 9.5mm lead length @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	0.25			A
Peak forward surge current 10ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	$I_{FSM}$	15.0			A
Maximum instantaneous forward voltage @ 0.25A	$V_F$	2.5			V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at Rated DC blocking voltage @ $T_A=100^\circ\text{C}$	$I_R$	10.0 150.0			$\mu\text{A}$
Maximum reverse recovery time (Note1)	$t_{rr}$	100			ns
Typical junction capacitance (Note2)	$C_J$	20	15		pF
Typical thermal resistance (Note3)	$R_{\theta JL}$	20			$^\circ\text{C/W}$
Operating junction temperature range	$T_J$	- 55 ----- + 150			$^\circ\text{C}$
Storage temperature range	$T_{STG}$	- 55 ----- + 150			$^\circ\text{C}$

Note: 1. Measured with  $I_F=0.5\text{A}$ ,  $I_R=1\text{A}$ ,  $I_{rr}=0.25\text{A}$ .  
 2. Measured at 1.0MHz and applied reverse of 4.0V DC.  
 3. Thermal resistance from junction to ambient.

**FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**

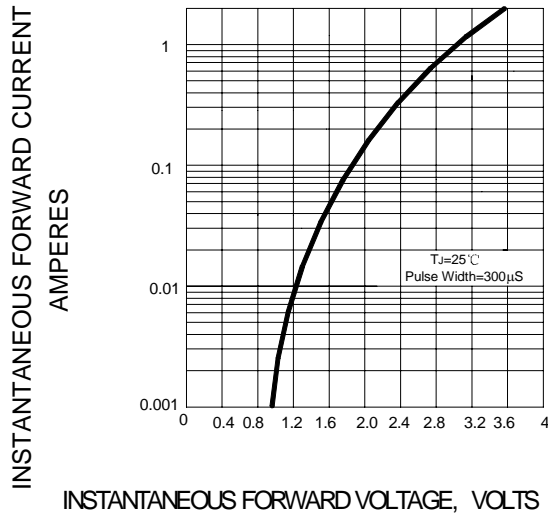


NOTES: 1. RISE TIME = 7ns MAX INPUT IMPEDANCE = 1MΩ, 22pF.  
 2. RISE TIME = 10ns MAX SOURCE IMPEDANCE = 50 Ω.

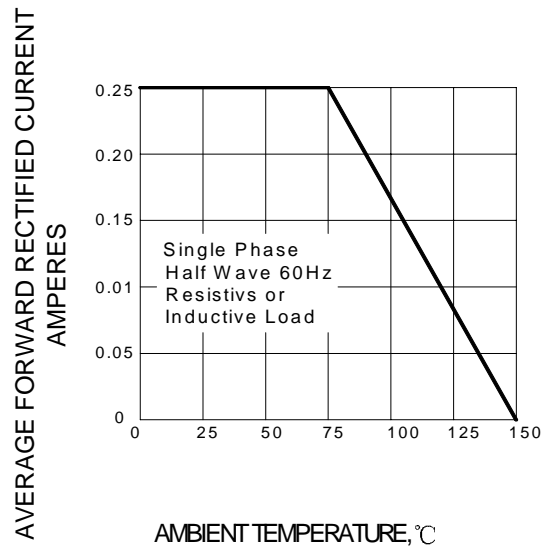


SET TIME BASE FOR 10/20 ns/cm

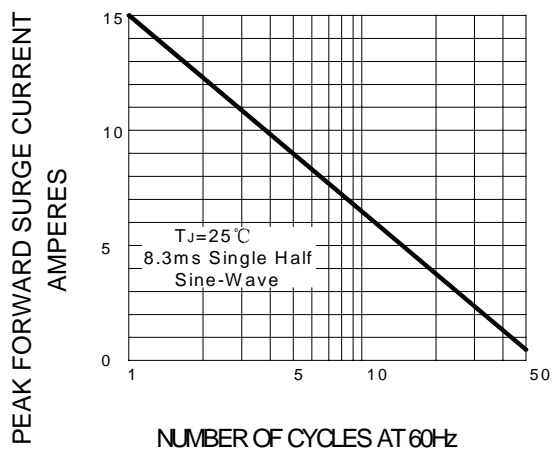
**FIG.2 – TYPICAL FORWARD CHARACTERISTIC**



**FIG.3 – FORWARD DERATING CURVE**



**FIG.4 – PEAK FORWARD SURGE CURRENT**



**FIG.5 – TYPICAL JUNCTION CAPACITANCE**

